

Introduction:

P20 pressure sensors are based on microfused technology which employs micromachined silicon piezoresistive strain gages fused with high temperature glass to a stainless steel diaphragm.

The wetted material is made of stainless steel, designed as all welded structure without 0ring, High burst pressure is achieved by its solid structure. The plastic housing was made of PA66+30%GF, Which make sure the sensor with low cost and excellent weatherproof.

Each sensor was strictly temperature compensated for both zero and span, With the performance of high accuracy and excellent long term stability.

There are various of signal outputs are available, including:0-100mV, I²C, 4-20mA, 0.5-4.5V, 0-5V, 1-5V etc, Different pressure ports are optional as well.

The amplified sensors meet the latest heavy industrial CE requirements, including surge protection. The circuit is protected from reverse wiring at input and short circuit at output.

Features:

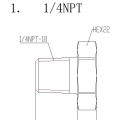
- Pressure Range: 0-3.5MPa...35MPa
- Stainless steel welded, without 0-ring
- 5X burst pressure
- Nylon Housing; low cost

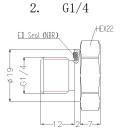
Application:

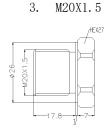
- Hydraulic/Pneumatic Control Systems
- **Energy and Water Management**
- Pumps and Compressors
- Automotive Test Stands
- Agriculture Equipment

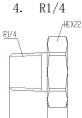
Dimensions (mm)

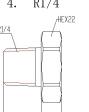
Pressure port and Hex





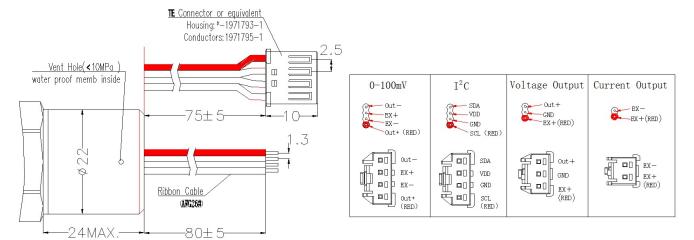








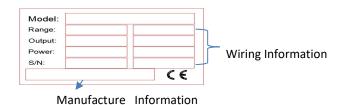
Housing & Cable/Connector





<u>Pressure sensor (Microfused)</u> <u>Plastic Housing</u>

Label



General items of Specifications						
Pressure Range		0−3. 5MPa···35MPa				
Over pressure		2 times of rated pressure				
Burst pressure	е	5 times of rated pressrue or 150MPa whichever is less				
Materials		Wetted materials: Stainless steel 17-4PH and 304; Housing: Nylon PA66+30%GF				
Operation Tem	p.	-40~105°C				
Insulation Resistance		50MΩ/250V				
Water proof		IP65				
Anti-Shock		50g, 11MSEC HALF SINE SHOCK PER MIL-STD-202G, METHOD 213B, CONDITION A.				
Anti-Vibration	n	± 20 g MIL-STD-810C, PROCEDURE 514.2, FIGURE 514.2-2, CURVE L.				
Life		>10 ⁷ full range pressure				
Long term	Zero	0. 2				
stability (%FS annual)	Span	0. 1				

Specifications of amplified sensors

25° C (unless otherwise specified)

Parameters	Min.	Typical	Max.		
Output	4-20mA;	5V; 0-5V			
Accuracy (%FS) combined NLH ¹ , HYS and REP.		±0.05	±0.1		
Zero Error(%FS)		±0.25	±0.5		
Span Error(%FS)		±0.25	±0.5		
Compensation Temp. (°C)	-10		70		
Total error band(%FS) ²		±0.5	±1		
Frequency (Hz)	1k				
Load Resistance $RL(\Omega)$					
Current output	RL < 50X (Vsupply-8)				
Voltage outpu	RL>20k				

Circuit with reverse polarity protection

CE Compliance:

EN55032 Emissions Class A&B

IEC61000-4-2 (ESD) : 15KV (air) /8KV (contact)

IEC61000-4-3 Radiated, Radio-Frequency Electromagnetic Field Immunity (10V/m, 80MHZ~1GHZ)

IEC61000-4-4 Electrial Fast Transient Immunity (1kV)

IEC61000-4-5 Surge Immunity

Input to Output: $\pm 1kV/42\Omega$; Leads to Case: $\pm 1kV/12\Omega$;

Output to GND: $\pm 1 \text{kV}/42 \Omega$ (The third item only apply to Voltage Output)

IEC61000-4-6 Immunity to conducted disturbances Induced by Radio Frequency Fields

150kHZ~80MHZ, 3V Level for current output; 10V Level for Voltage output

IEC61000-4-9 Pulse Magnetic Field Immunity (100A/m Peak)

For CE compliance tests, allowed output deviation within: $\pm 1\%$ FS(current output); $\pm 1.5\%$ FS(voltage output)



Specifications	of I ² C	der 25°C (unless otherwise specified)					
Param	Parameters		Typical	Max.	Notes		
Interface Type		I ² C (ADDR, OX28H)			SPI (optional)		
Accuracy (%FS)		-0. 15	±0.1	0. 15	combined linearity ¹ , hysteresis and repeatability.		
Total Error B	and (%FS) ²	-0. 75	±0.5	0. 75			
Output Type		10% 90% (A type)		/pe)	5%-95%(B type) Optional		
Zero Pressure	Output		666				
Full Scale Pressure Output(FS)			399A		Count Hex		
Resolution-Pressure(%FS)		0. 008			14bits		
Temp. Accuracy (°C)		-2		2	over the compensated temperature range		
Resolution - Temp. (°C)			0. 1		8~11bits		
Compensated Temp. (°C)		-10		70			
Input Voltage(V)		2. 7	3. 3	5. 5			
Current	Non-Sleep		2. 7mA		default		
consumption	Sleep mode		2μ A		optional		
Load Resistance (KΩ)		10					
Response Frequency (HZ)			2K				

Specifications of 0-100mV	output Excitation	5VDC under 25° C (unless ot	herwise specified)	
Parameters	Parameters Min.		Max.	
Accuracy (%FS)				
Non-Linearity ¹		±0.15	±0.25	
Hysteresis		±0.1	±0.15	
Repeatability		±0.1	±0.15	
Output (mV)				
Zero	-1	0	1	
Span (FS)	99	100	101	
Temp. characters				
Compensation Temp(°C)	-10		70	
Zero Temp. error (%FS)		±0.75	±1	
Span Temp.error(%FS)		±1	±1.5	
Supply Voltage		5VDC	10VDC	
Input Resistance	5. 0	6. 6	8. 0	
Output Resistance	3. 5	4. 4	5. 5	

Remark:

- 1. BFSL(best fitting straight line)
- 2. Total error band: total output error including Zero, Span, non-linearity, temp. erorr within compensated temperature range.



Pressure sensor (Microfused) Plastic Housing

Mode I		Exitation			Output		
P21		5V			0.5-4.5V (Ratiometric)		
P22		8-30V			0-	-5V	
P23		8-30V		4-20mA			
P24		8-30V		1-5V			
P25		3.3V		I^2C		² C	
P26		5V		0-100mV			
	Code		re Range	Vent G	auge	Sealed Gauge	
	3.5M		.5MPa	*			
	7M		7MPa	*			
	10M	0-10Mpa				*	
	20M	0-20MPa				*	
	35M	0-35MPa				*	
	XX	Others Code					
				Pressure Port			
			1		1/4NPT		
		2		G 1/4			
		4		D1 /4	M20X1.5 (old ZG1/4		
		5		K1/4	1/8NPT	i /	
		X			Others		
		A	Code Electric outlet		c outlet		
				1 Ribbon Cable			
			2				
		X		Others			
Example:							
P23	3.5M	1	1				
4-20-4	0_2 EMD ₀	1 /4NDT	Dikhan sahia				

P23	3.5M	1	1		
4-20mA	0−3. 5MPa	1/4NPT	Ribbon cable		Model:P23-3.5M-11